L Number	Hits	Search Text	DB	Time stamp
-	403	(257/536).CCLS.	USPAT	2002/04/01 09:32
-	207	(257/537).CCLS.	USPAT	2002/03/27 17:08
-	183	(257/538).CCLS.	USPAT	2002/03/27 17:10
-	564	(438/238).CCLS.	USPAT	2002/03/27 17:11
-	231	(438/384).CCLS.	USPAT	2002/03/28 09:06
-	186	(438/385).CCLS.	USPAT	2002/03/28 09:08
-	2630	shallow adj4 trench adj4 isolation	USPAT	2002/03/28 09:53
-	253	(shallow adj4 trench adj4 isolation) and resistor$1	USPAT	2002/03/28 09:53
-	237	((shallow adj4 trench adj4 isolation) and resistor$1) and (insulat$3 or dielectric or SiO or (silicon adj oxide))	USPAT	2002/03/28 09:54
-	17020	(trench groove grooved) near3 (oxide dioxide isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:25
-	1231	((trench groove grooved) near3 (oxide dioxide isolation)) and resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:26
-	225	((trench groove grooved) near3 (oxide dioxide isolation)) same resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:26
-	98	((trench groove grooved) near3 (oxide dioxide isolation)) with resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:26
-	29303	(resistive resistivity resistor) near20 (isolation STI FOX field LOCOS)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:27
-	25231	(resistive resistor) near20 (isolation STI FOX field LOCOS)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:28
-	2951	(resistive resistor) near20 ((si or silicon) near3 (poly or polycrystalline))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:30
-	3804	(resistive resistivity resistor) near20 ((si or silicon) near3 (poly or polycrystalline))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:30
-	597	((resistive resistivity resistor) near20 (isolation STI FOX field LOCOS)) and ((resistive resistivity resistor) near20 ((si or silicon) near3 (poly or polycrystalline)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:31
-	1	(((resistive resistivity resistor) near20 (isolation STI FOX field LOCOS)) and ((resistive resistivity resistor) near20 ((si or silicon) near3 (poly or polycrystalline)))) and (dummy adj gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:32

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-	92	(((resistive resistivity resistor) near20 (isolation STI FOX field LOCOS)) and ((resistive resistivity resistor) near20 ((si or silicon) near3 (poly or polycrystalline)))) and ((resistive resistivity resistor) near20 (spac$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 15:39
-	18	(("5780333") or ("5837592") or ("5856225") or ("5866947") or ("6033963") or ("6093628") or ("6171910") or ("6184114") or ("6221776") or ("6251729") or ("6255698") or ("6261935") or ("6284609") or ("6297107") or ("6300201") or ("6303418") or ("6333223") or ("6333540")).PN.	USPAT	2002/03/28 15:42
-	21	(sti (shallow near10 trench)) near100 resistor	USPAT	2002/03/28 15:43
-	23	(sti (shallow near10 trench)) near100 resistor	USPAT; US-PGPUB	2002/03/28 15:43
-	7	(("6346736") or ("6319772") or ("6297126") or ("6265302") or ("6083785") or ("5759886") or ("5652176")).PN.	USPAT	2002/04/01 09:14
-	0	6346736.urpn.	USPAT	2002/04/01 09:14
-	0	6319772.urpn.	USPAT	2002/04/01 09:14
-	0	6297126.urpn.	USPAT	2002/04/01 09:14
-	0	6265302.urpn.	USPAT	2002/04/01 09:14
-	1	6083785.urpn.	USPAT	2002/04/01 09:15
-	3	5759886.urpn.	USPAT	2002/04/01 09:16
-	17	5652176.urpn.	USPAT	2002/04/01 09:16
-	156	438/382.ccls.	USPAT	2002/04/01 10:00
-	430	257/379.ccls.	USPAT	2002/04/01 10:25
-	167	257/380.ccls.	USPAT	2002/04/01 10:36
-	56	257/381.ccls.	USPAT	2002/04/01 10:56
-	661	438/424.ccls.	USPAT	2002/04/01 12:30
-	106	438/229.ccls.	USPAT	2002/04/01 12:30